Freescale Semiconductor Technical Data

Document Number: MHW8222BN Rev. 6, 4/2006

RoHS

RMATIC

CHIVE

CATV Amplifier Module

Features

- · Specified for 77-, 110- and 128-Channel Loading
- Excellent Distortion Performance
- Silicon Bipolar Transistor Technology •
- Unconditionally Stable Under All Load Conditions •

Applications

- CATV Systems Operating in the 40 to 860 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk • Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications •
- Output Stage Amplifier on Applications Requiring Low Power Dissipation •

Description

- 24 Vdc Supply, 40 to 860 MHz, CATV Forward Amplifier Module
- Replaced MHW8222B. There are no form, fit or function changes with this part replacement.
- **RoHS** Compliant ٠

CASE 1302-01, STYLE 1

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DC Supply Voltage	V _{CC}	+28	Vdc
RF Input Voltage (Single Tone)	V _{in}	+ 70	dBmV
Operating Case Temperature Range	T _C	- 20 to +100	°C
Storage Temperature Range	T _{stg}	- 40 to +100	°C

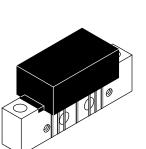
Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_C = + 30° C, 75 Ω system unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	_	860	MHz
Power Gain	f = 50 MHz f = 860 MHz	G _p	21.4 21.8	21.9 22.7	22.4 24	dB
Slope (f = 40 - 860 MHz)		S	0.1	0.8	1.5	_
Gain Flatness (Peak To Valley)	(f = 40 - 860 MHz)	G _F	_	0.4	0.6	_
Input/Output Return Loss @ f = 40 MHz		IRL/ORL	20	24	_	dB
Derate Return Loss @ f > 40 MHz		RLD	_	_	0.009	dB/MHz
Composite Second Order (V _{out} = +38 dBmV/ch; 128 Channels) (V _{out} = +40 dBmV/ch; 110 Channels) (V _{out} = +44 dBmV/ch; 77 Channels)		CSO ₁₂₈ CSO ₁₁₀ CSO ₇₇		- 68 - 64 - 65	- 60 - 61 - 62	dBc





860 MHz 22.7 dB GAIN 128-CHANNEL CATV AMPLIFIER MODULE





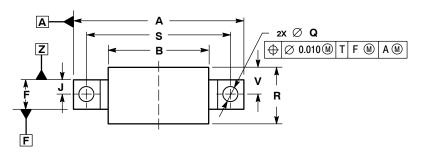
Characteristic	Symbol	Min	Тур	Max	Unit
Cross Modulation Distortion					dBc
(V _{out} = +38 dBmV/ch, 128-Channel @ Fm = 55.25 MHz)	XMD ₁₂₈	_	- 65	- 63	
(V _{out} = +40 dBmV/ch, 110-Channel @ Fm = 55.25 MHz)	XMD ₁₁₀	_	- 63	- 60	
(V _{out} = +44 dBmV/ch, 77-Channel @ Fm = 55.25 MHz)	XMD ₇₇	—	- 59	- 56	
Composite Triple Beat					dBc
(V _{out} = +38 dBmV/ch, 128-Channels, Worst Case)	CTB ₁₂₈	_	- 66	- 64	
(V _{out} = +40 dBmV/ch, 110-Channels, Worst Case)	CTB ₁₁₀	_	- 64	- 61	
(V _{out} = +44 dBmV/ch, 77-Channels, Worst Case)	CTB ₇₇	_	- 65	- 62	
Noise Figure f = 50 MHz	NF	_	3.7	4.5	dB
f = 750 MHz		_	5	6.5	
f = 860 MHz		—	5.6	7	
DC Current	IDC	180	220	240	mA

RF Device Data Freescale Semiconductor

ARCHIVE INFORMATION

MHW8222BN

PACKAGE DIMENSIONS



– 2X U

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4X G

∠₂x Ø Y

⊕ Ø 0.010 M Z T A M

2X 6-32UNC-2B

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🕀 Ø 0.020 🕅 T A 🕅 X

– 7X D

⊕ Ø 0.010 ₪ Z T A ₪

С

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NOTES: 1. DIMENSIONS ARE IN INCHES. 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
Е	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100) BSC	2.540 BSC		
J	0.15	6 BSC	3.962 BSC		
K	0.315	0.355	8.001	9.017	
L	1.000 BSC		25.400 BSC		
Ν	0.165 BSC		4.191 BSC		
Ρ	0.100 BSC		2.540 BSC		
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500 BSC		38.100 BSC		
U	0.200 BSC		5.080 BSC		
V		0.250		6.350	
W	0.435		11.049		
X	0.400 BSC		10.160 BSC		
Υ	0.152	0.163	3.861	4.140	
Ζ	0.009	0.011	0.229	0.279	

STYLE 1:	
PIN 1.	rf input
	GROUND
3.	GROUND
4.	DELETED
5.	VDC
6.	DELETED
7.	GROUND
8.	GROUND
9.	RF OUTPUT

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CASE 1302-01 **ISSUE E**

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